NSN 5961-00-755-4350

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-755-4350 **Inclosure Material:** Metal **Overall Length:** 0.410 inches **Terminal Length:** 0.370 inches **Overall Diameter:** 1.560 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Terminal Circle Diameter:** 0.430 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 12.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 80.0 degrees celsius junction **Special Features:** Two no. 16 mtg holes spaced 1.187 in. C to c; junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Specification Data:** 80131-release1748 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

NSN 5961-00-755-4350 Transistor - Page 2 of 2



Fiig:

A110a0